## NSN 5962-01-420-9577

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View Online at https://aerobasegroup.com/nsn/5962-01-420-9577

Body Length:
0.358 inches
Body Width:
0.358 inches
Body Height:
0.100 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Pacer dawn
Features Provided:
Electrostatic sensitive and monolithic and programmed and 3-state output and bipolar
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
14 input
Criticality Code Justification:
Cbbl
Case Outline Source And Designator:
C-4 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, programmed (prom 93z665a)
Voltage Rating And Type Per Characteristic:
-0.3 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
55.00 nanoseconds propagation delay time, high to low level output and 55.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Programmed
Special Features:
Altered item, made from device 82009023x, cage 14933, microcircuit, memory, digital, bipolar 64k (8k x 8) prom, monolithic silicon;

**Test Data Document:** 

program p/n 7816354p758

96906-mil-std883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal 1	ype And	Quantity:
20 leadless	8	

ZU leadles.

Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

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